

製品概要

DTA143EM3: PNP Bipolar Digital Transistor (BRT)

技術情報は、データシートをご参照ください。

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

特長

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are PbFree, Halogen Free/BFR Free and are RoHS Compliant

電氣的仕様

製品	Compliance	Status	Polarity	I_C Continuous (A)	V_{BRICE0} Min (V)	h_{FE} Min	R1 (k Ω)	R2 (k Ω)	R1/R2 Typ	$V_{i(off)}$ Max (V)	$V_{i(on)}$ Min (V)	Package Type
DTA143EM3T5G	Pb-free Halide free	Active	PNP	0.1	50	15	4.7	4.7	1	0.5	3	SOT-723-3
NSVDTA143EM3T5G	AEC Qualified PPAP Capable Pb-free Halide free	Active	PNP	0.1	50	15	4.7	4.7	1	0.5	3	SOT-723-3

詳細は、弊社 www.onsemi.jp の営業または販売代理店にお問い合わせください。

8/18/2019 作成